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April 2015

# FGH40N65UFD\_F085

## 650 V, 40 A Field Stop IGBT

### Features

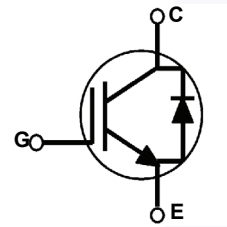
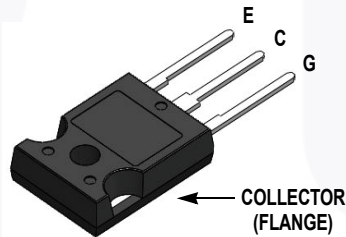
- High Current Capability
- Low Saturation Voltage:  $V_{CE(sat)} = 1.8\text{ V @ } I_C = 40\text{ A}$
- High Input Impedance
- Fast Switching
- RoHS Compliant
- Qualified to Automotive Requirements of AEC-Q101

### Applications

- Automotive Chargers, Converters, High Voltage Auxiliaries
- Inverters, PFC, UPS

### General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.



### Absolute Maximum Ratings

Symbol	Description	Ratings	Unit
$V_{CES}$	Collector to Emitter Voltage	650	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 20$	V
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	80	A
	Collector Current @ $T_C = 100^\circ\text{C}$	40	A
$I_{CM(1)}$	Pulsed Collector Current @ $T_C = 25^\circ\text{C}$	120	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	290	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	116	W
$T_J$	Operating Junction Temperature	-55 to +150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

**Notes:**

1: Repetitive rating: Pulse width limited by max. junction temperature

### Thermal Characteristics

Symbol	Parameter	Typ	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction to Case	0.43	$^\circ\text{C/W}$
$R_{\theta JC}(\text{Diode})$	Thermal Resistance, Junction to Case	1.45	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	40	$^\circ\text{C/W}$

FGH40N65UFD\_F085 650 V, 40 A Field Stop IGBT

## Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGH40N65UFDU_F085	FGH40N65UFD	TO-247	Tube	N/A	N/A	30

## Electrical Characteristics of the IGBT T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>Off Characteristics</b>						
$BV_{CES}$	Collector to Emitter Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 250\ \mu\text{A}$	650	-	-	V
$\Delta BV_{CES}$ $\Delta T_J$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0\text{ V}, I_C = 250\ \mu\text{A}$	-	0.6	-	V/°C
$I_{CES}$	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0\text{ V}$	-	-	250	$\mu\text{A}$
$I_{GES}$	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0\text{ V}$	-	-	±400	nA
<b>On Characteristics</b>						
$V_{GE(th)}$	G-E Threshold Voltage	$I_C = 250\ \mu\text{A}, V_{CE} = V_{GE}$	4.0	5.2	6.5	V
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	$I_C = 40\text{ A}, V_{GE} = 15\text{ V}$	-	1.8	2.4	V
		$I_C = 40\text{ A}, V_{GE} = 15\text{ V}, T_C = 125^\circ\text{C}$	-	2.0	-	V
<b>Dynamic Characteristics</b>						
$C_{ies}$	Input Capacitance	$V_{CE} = 30\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$	-	1860	-	pF
$C_{oes}$	Output Capacitance		-	200	-	pF
$C_{res}$	Reverse Transfer Capacitance		-	65	-	pF
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400\text{ V}, I_C = 40\text{ A}, R_G = 10\ \Omega, V_{GE} = 15\text{ V}, \text{Inductive Load}, T_C = 25^\circ\text{C}$	-	23	-	ns
$t_r$	Rise Time		-	35	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	126	-	ns
$t_f$	Fall Time		-	26	60	ns
$E_{on}$	Turn-On Switching Loss		-	1.28	-	mJ
$E_{off}$	Turn-Off Switching Loss		-	0.50	-	mJ
$E_{ts}$	Total Switching Loss		-	1.78	-	mJ
$t_{d(on)}$	Turn-On Delay Time	$V_{CC} = 400\text{ V}, I_C = 40\text{ A}, R_G = 10\ \Omega, V_{GE} = 15\text{ V}, \text{Inductive Load}, T_C = 125^\circ\text{C}$	-	21	-	ns
$t_r$	Rise Time		-	39	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	131	-	ns
$t_f$	Fall Time		-	72	-	ns
$E_{on}$	Turn-On Switching Loss		-	1.62	-	mJ
$E_{off}$	Turn-Off Switching Loss		-	0.79	-	mJ
$E_{ts}$	Total Switching Loss		-	2.41	-	mJ
$Q_g$	Total Gate Charge	$V_{CE} = 400\text{ V}, I_C = 40\text{ A}, V_{GE} = 15\text{ V}$	-	119	-	nC
$Q_{ge}$	Gate to Emitter Charge		-	14	-	nC
$Q_{gc}$	Gate to Collector Charge		-	64	-	nC

**Electrical Characteristics of the Diode** T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max	Unit	
V <sub>FM</sub>	Diode Forward Voltage	I <sub>F</sub> = 20 A	T <sub>C</sub> = 25°C	-	1.80	2.6	V
			T <sub>C</sub> = 125°C	-	1.71	-	
t <sub>rr</sub>	Diode Reverse Recovery Time	I <sub>F</sub> = 20 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25°C	-	65	-	ns
			T <sub>C</sub> = 125°C	-	215	-	
Q <sub>rr</sub>	Diode Reverse Recovery Charge	I <sub>F</sub> = 20 A, di <sub>F</sub> /dt = 200 A/μs	T <sub>C</sub> = 25°C	-	145	-	nC
			T <sub>C</sub> = 125°C	-	775	-	

## Typical Performance Characteristics

Figure 1. Typical Output Characteristics

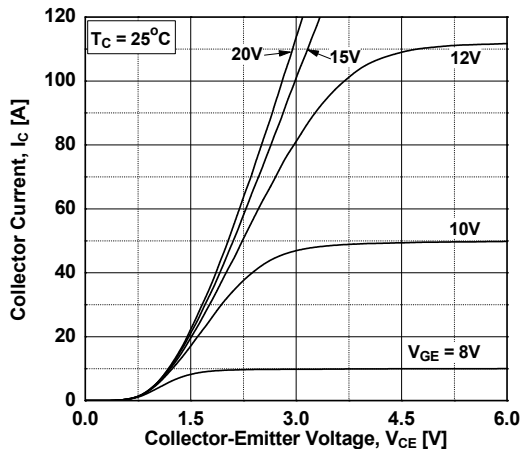


Figure 2. Typical Output Characteristics

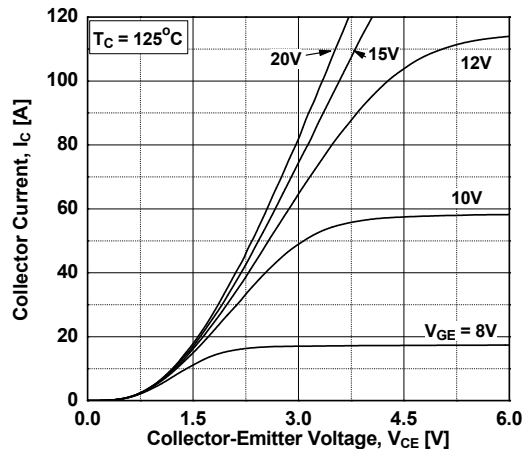


Figure 3. Typical Saturation Voltage Characteristics

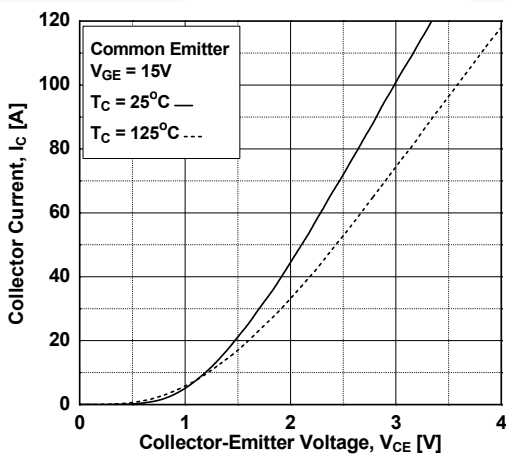


Figure 4. Transfer Characteristics

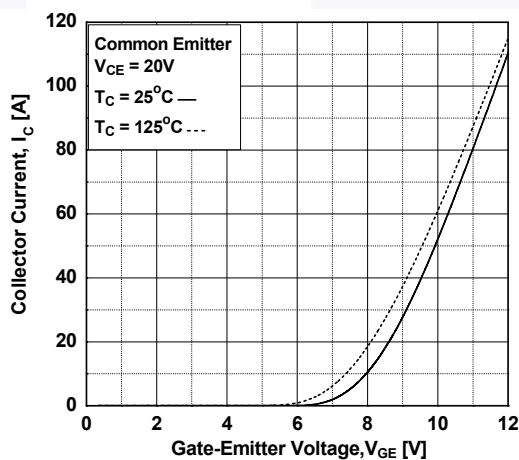


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

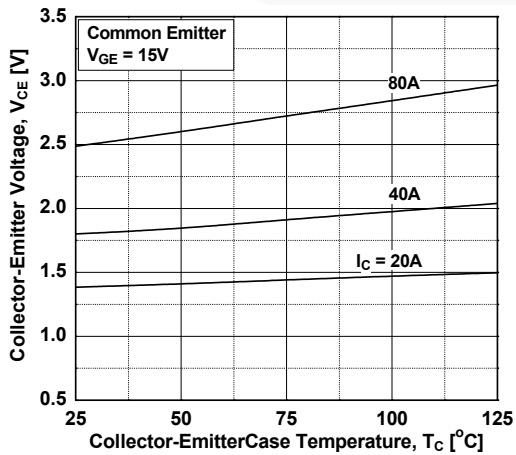
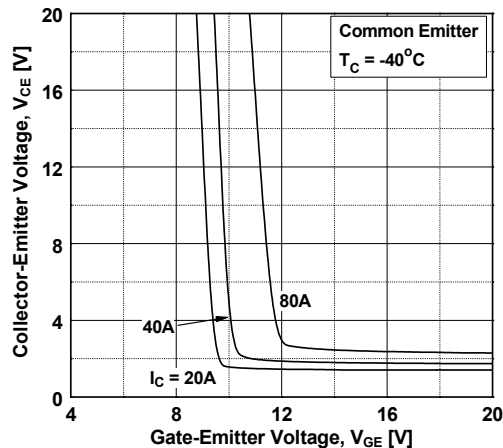


Figure 6. Saturation Voltage vs. Vge



## Typical Performance Characteristics

Figure 7. Saturation Voltage vs.  $V_{GE}$

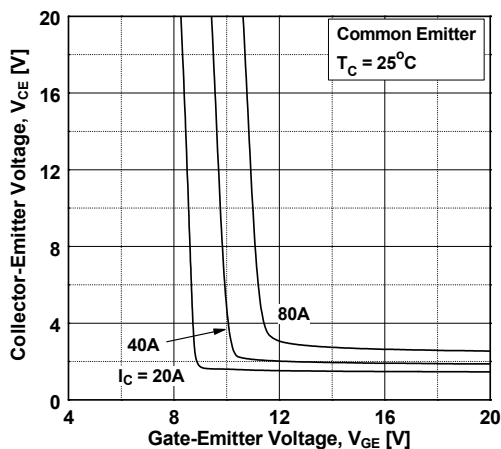


Figure 8. Saturation Voltage vs.  $V_{GE}$

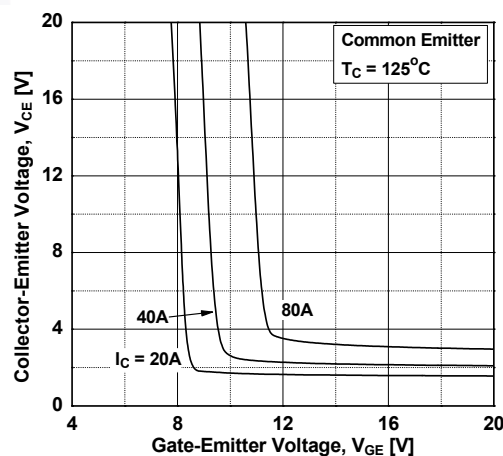


Figure 9. Capacitance Characteristics

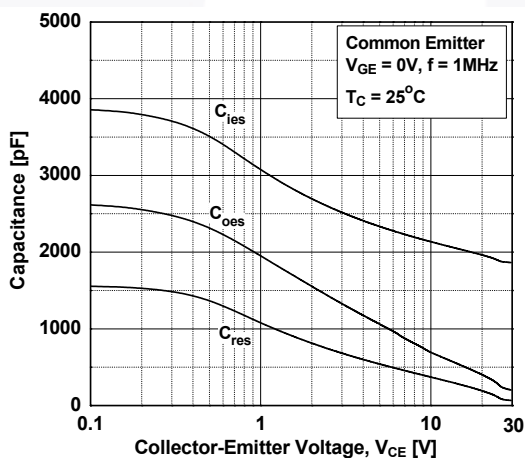


Figure 10. Gate charge Characteristics

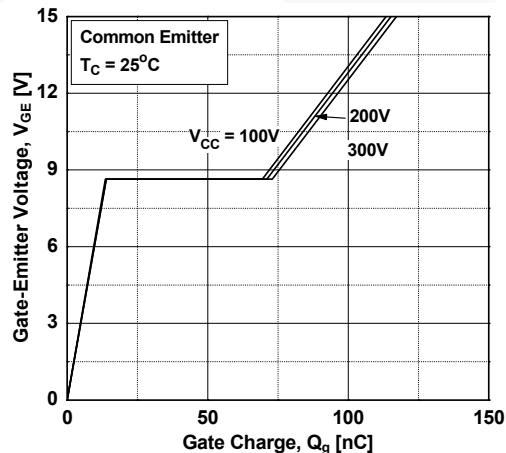


Figure 11. SOA Characteristics

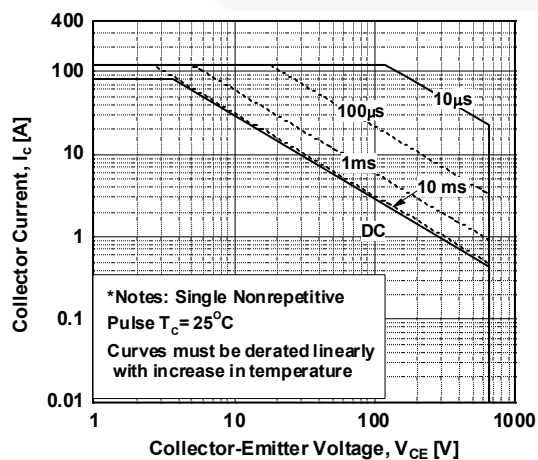
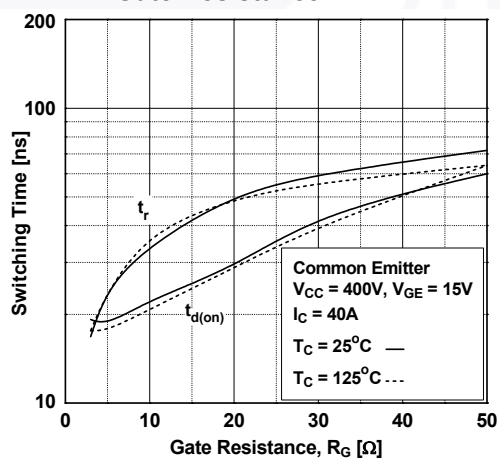
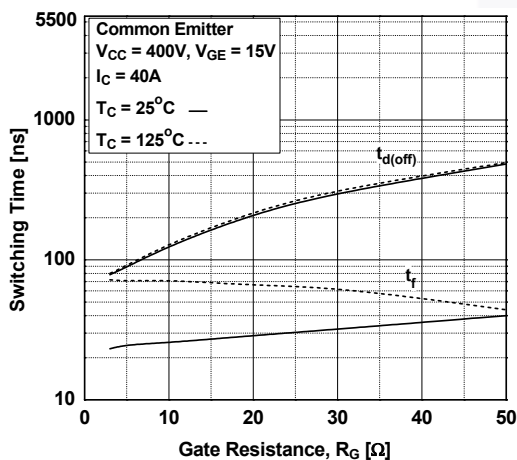


Figure 12. Turn-on Characteristics vs. Gate Resistance

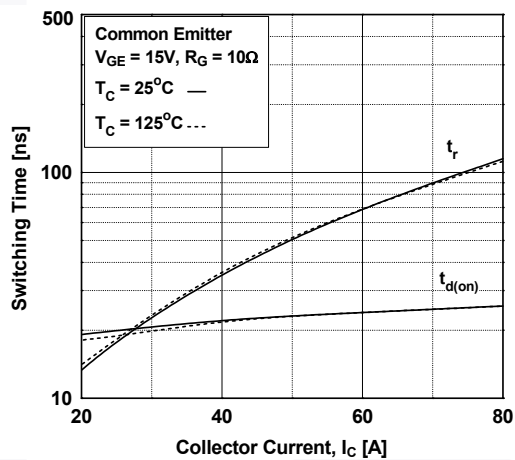


## Typical Performance Characteristics

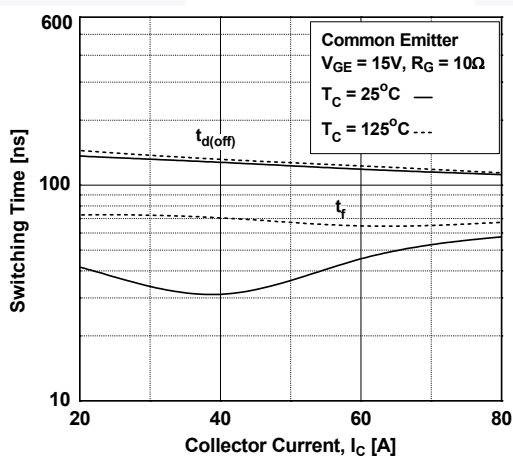
**Figure 13. Turn-off Characteristics vs. Gate Resistance**



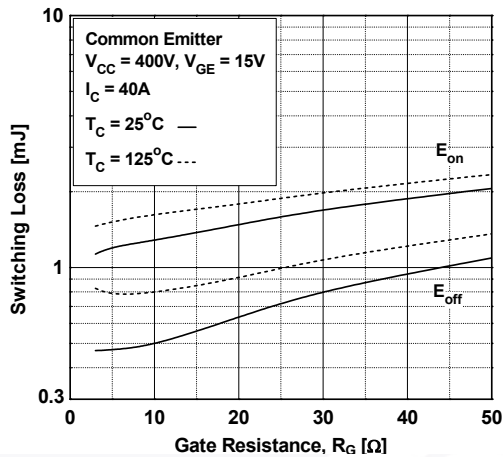
**Figure 14. Turn-on Characteristics vs. Collector Current**



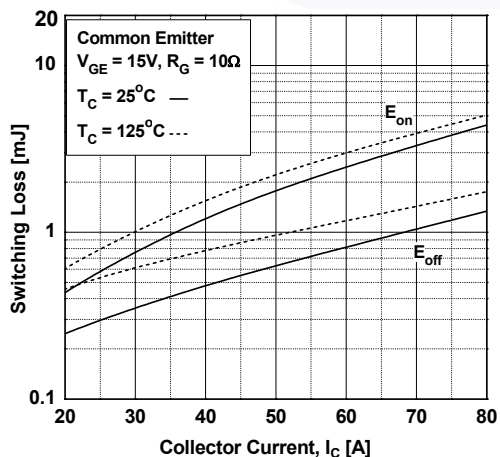
**Figure 15. Turn-off Characteristics vs. Collector Current**



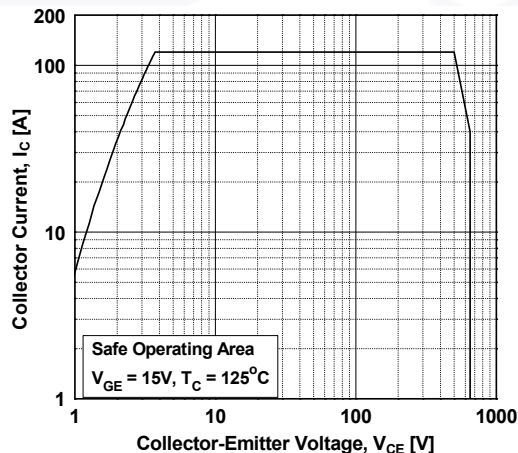
**Figure 16. Switching Loss vs. Gate Resistance**



**Figure 17. Switching Loss vs. Collector Current**



**Figure 18. Turn off Switching SOA Characteristics**



## Typical Performance Characteristics

Figure 19. Forward Characteristics

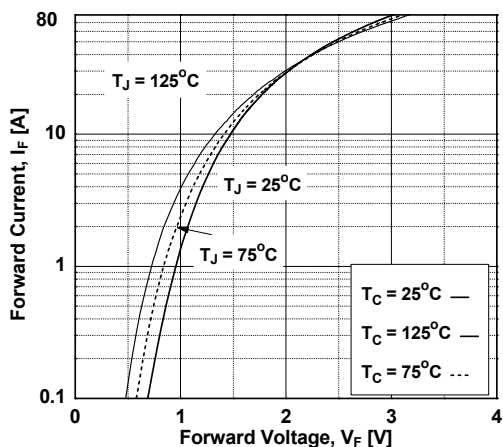


Figure 20. Reverse Current

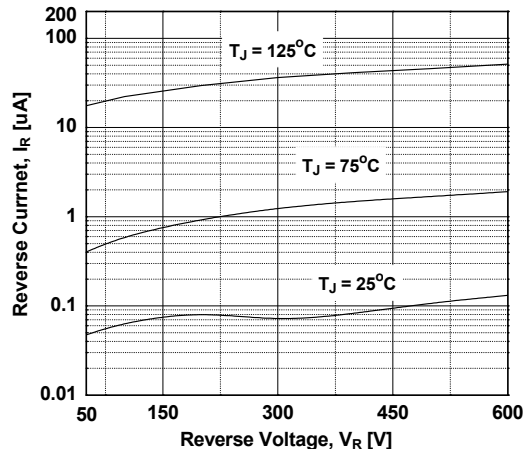


Figure 21. Stored Charge

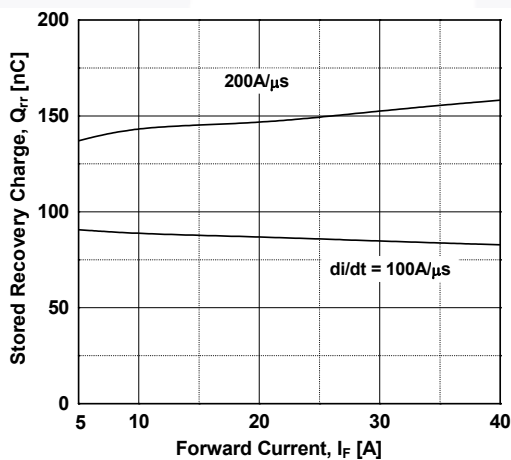


Figure 22. Reverse Recovery Time

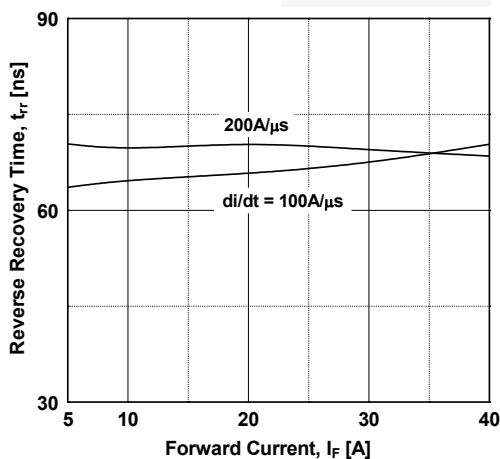
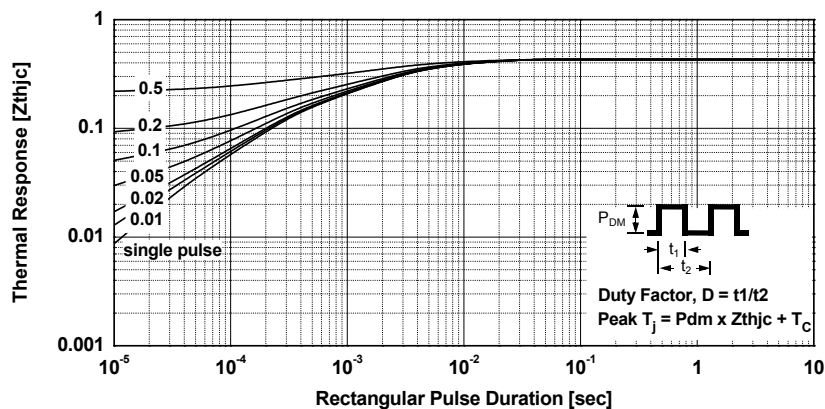
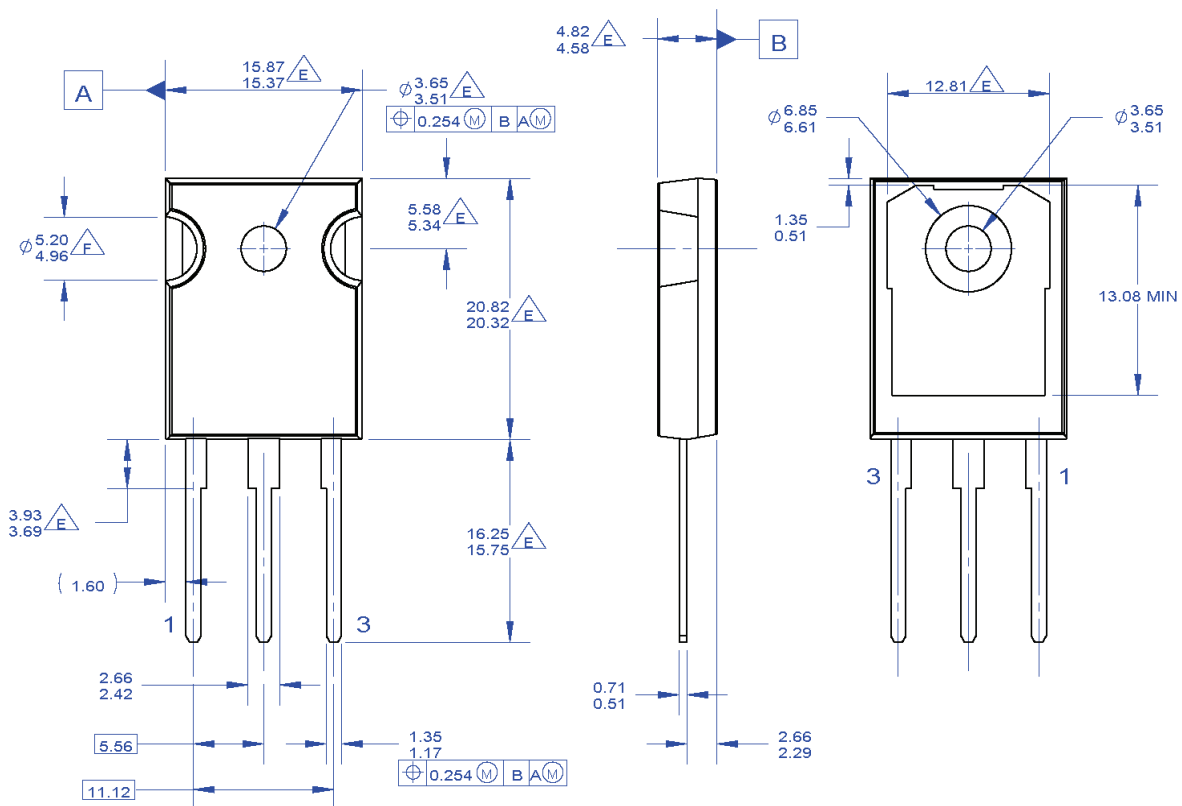


Figure 23. Transient Thermal Impedance of IGBT







### Mechanical Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED.

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- D. DRAWING CONFORMS TO ASME Y14.5 - 1994

-  DOES NOT COMPLY JEDEC STANDARD VALUE
-  NOTCH MAY BE SQUARE
- G. DRAWING FILENAME: MKT-TO247A03\_REV03

**Figure 24. TO-247 3L - TO-247,MOLDED,3 LEAD,JEDEC VARIATION AB**

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| Awinda®  | Global Power ResourceSM                         | PowerTrench®                          | TinyBuck®        |
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| Fairchild Semiconductor®   | MotionMax™                                      | SuperSOT™-3                           | VisualMax™       |
| FACT Quiet Series™   | MotionGrid®                                     | SuperSOT™-6                           | VoltagePlus™     |
| FACT®  | MTI®  | SuperSOT™-8                           | XS™              |
| FAST®  | MTx®  | SupreMOS®                             | Xsens™           |
| FastvCore™   | MVN®  | SyncFET™                              | 仙童™              |
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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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